NSN 5961-01-214-2092

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View Online at https://aerobasegroup.com/nsn/5961-01-214-2092 **Inclosure Material:** Plastic **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Height:** 0.165 inches **Overall Width:** 0.205 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-92 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 collector to base voltage/static/emitter open and 15.0 collector to emitter voltage/static/base open and 2.0 emitter to base voltage, static, collector open and 15.0 collector to base voltage, dc and 10.0 collector to emitter voltage, dc **Current Rating Per Characteristic:** 50.00 nanoamperes zero-gate-voltage source current preset and 8.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 300.0 watts small-signal input power, common-collector preset **Transfer Ratio:** 200.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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